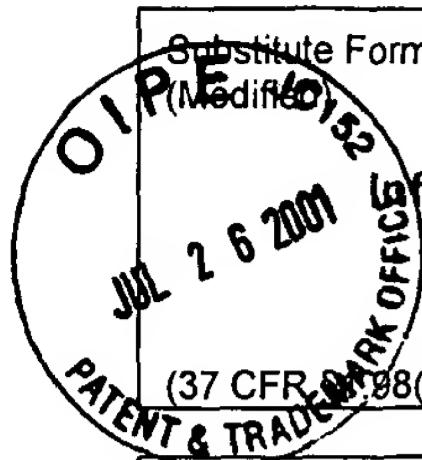


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Dkong
8/17/01Substitute Form PTO-1449
(Modified)U.S. Department of Commerce
Patent and Trademark OfficeAttorney's Docket No.
12732-007001Application No.
09/768,618
**Information Disclosure Statement
by Applicant**
(Use several sheets if necessary)

(37 CFR 1.98(b))

Applicant
Setsuo NAKAJIMA et al.Filing Date
January 25, 2001Group Art Unit
Unknown**U.S. Patent Documents**

Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
SDI	AA	4,330,363	05/18/82	Biegesen et al.			
SDI	AB	4,466,179	08/21/84	Kasten			
SDF	AC	5,145,808	09/08/92	Sameshima et al.			
SDF	AD	5,194,853	03/16/93	Asada			
SDI	AE	5,247,375	09/21/93	Mochizuki et al.			
SDI	AF	5,264,383	11/23/93	Young			
SDI	AG	5,365,875	11/22/94	Asai et al.			
SDI	AH	5,372,836	12/13/94	Imahashi et al.			
SDF	AI	5,403,762	04/04/95	Takemura			
SDI	AJ	5,403,772	04/04/95	Zhang et al.			
SDF	AK	5,413,958	05/09/95	Imahashi et al.			
SDF	AL	5,414,442	05/09/95	Yamazaki et al.			
SDI	AM	5,432,122	07/11/95	Chae			
SDF	AN	5,449,637	09/12/95	Saito et al.			
SDF	AO	5,453,858	09/26/95	Yamazaki			
SDI	AP	5,477,073	12/19/95	Wakai et al.			
SDF	AQ	5,514,879	05/07/96	Yamazaki			
SDF	AR	5,529,630	06/25/96	Imahashi et al.			
SDI	AS	5,563,426	10/08/96	Zhang et al.			
SDF	AT	5,570,105	10/29/96	Koyama			
SDI	AU	5,589,406	12/31/96	Kato et al.			
SDI	AV	5,614,732	03/25/97	Yamazaki			
SDI	AW	5,627,084	05/06/97	Yamazaki et al.			
SDI	AX	5,680,147	10/21/97	Yamazaki et al.			
SDF	AY	5,701,167	12/23/97	Yamazaki			
SDI	AZ	5,708,252	01/13/98	Shinohara et al.			
SDF	AAA	5,767,930	06/16/98	Kobayashi et al.			

Examiner Signature

Manetta Loyer

Date Considered

8/14/02

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 12732-007001	Application No. 09/768,618
Information Disclosure Statement by Applicant (Use several sheets if necessary)		Applicant Setsuo NAKAJIMA et al.	
(37 CFR §1.98(b))		Filing Date January 25, 2001	Group Art Unit Unknown



U.S. Patent Documents							
Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
SDI	ABB	5,849,601	12/15/98	Yamazaki			
SDI	ACC	5,859,445	01/12/99	Yamazaki			
SDI	ADD	5,939,731	08/17/99	Yamazaki et al.			
SDI	AEE	5,943,593	08/24/99	Noguchi et al.			
SDI	AFF	6,011,277	01/04/00	Yamazaki			
SDI	AGG	6,023,075	02/08/00	Yamazaki			
SDI	AHH	6,096,581	01/01/00	Zhang et al.			

Foreign Patent Documents or Published Foreign Patent Applications							
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation Yes No
	AII						

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
SDI	AJJ	Bonnel et al., "Polycrystalline Silicon Thin-Film Transistors with Two-Step Annealing Process," <u>IEEE Electron Device Letters</u> , 1993, 14(12):551-553
SDI	AKK	Fujieda et al., "Self-referenced Poly-Si TFT Amplifier Readout for a Linear Image Sensor," <u>IEEE</u> , 1993, pp. 587-590
SDI	ALL	Fuse et al., "Performance of Poly-Si Thin Film Transistors Fabricated by Excimer-Laser Annealing of SiH ₄ - and Si ₂ H ₆ - Source Low Pressure Vapor Deposited a-Si Films with or without Solid-Phase Crystallization," <u>Solid State Phenomena</u> , 1994, Vols. 37-38, pp. 565-570

Examiner Signature <i>Stanetta Chase</i>	Date Considered <i>8/14/02</i>
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	